## 論文 Original Paper

# Perovskite-type new boride in the Sc-Ni-B system

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**Abstract**: A search for perovskite-type new borides in the Sc-TM-B (TM = Ti, V, Cr, Mn, Fe, Co, and Ni) system has been carried out. As a result, the chemical formula of the compound ScNi<sub>3</sub>B<sub>0.5</sub> was obtained. This compound has the cubic perovskite-type structure (space group: Pm3m) with the lattice parameter a = 0.37760(7) nm. ScNi<sub>3</sub>B<sub>0.5</sub> exhibits metallic behavior down to 4.2 K. The magnetic susceptibility of ScNi<sub>3</sub>B<sub>0.5</sub> shows Pauli paramagnetism. No superconductivity appears down to the lowest temperature by the electric and magnetic measurements. The micro-Vickers hardness and oxidation resistivity in air are also reported for ScNi<sub>3</sub>B<sub>0.5</sub>.

Keywords: Perovskite-type boride, Electric property, Magnetic property, Hardness, Oxidation resistivity

#### 1. Introduction

Many studies of simple and complex perovskite-type oxides have been performed due to the interesting features as the superconductivity, the metal-insulator transition, ion conduction characteristics, dielectric properties, and ferro-elasticity [1–4]. On the other hand, there have been few studies on the non-oxide perovskite-type compound [5–8]. Systematic investigation of the synthesis and fundamental characterization of the non-oxide perovskite-type compounds is necessary.

In this study, we focus on the search for perovskite-type new ternary borides in the Sc-TM-B systems (TM = Ti, V, Cr, Mn, Fe, Co, and Ni).

### 2. Experimental details

#### 2.1 Synthesis

Polycrystalline samples of Sc-TM-B system were prepared by the arc melting method using 99.9% Sc (tips), 99.9% TM elements (tips) and 99.8% B (powder) as raw materials. These were weighed in the atomic ratio Sc:TM:B=1:3:1. The mixture of the starting materials,

1) 国土舘大学工学部都市システム工学科, 教授, 工学博士 Department of Civil and Environmental Engineering, Faculty of Engineering, Kokushikan University, Professor, Dr. of Engineering about 2 g for each sample, was placed on the water-cooled copper hearth in the reaction chamber. Argon was used as a protective atmosphere. A small amount of the residual oxygen in argon was eliminated by fusing a button of titanium. The starting materials were then melted for 3 min by argon arc plasma flame with dc power source at 20 V and 100 A. The samples were then turned over and melted three times under the same condition. Finally, synthesized samples were wrapped in the tantalum foil and annealed at 1573 K for 20 h under vacuum to ensure homogeneity.

#### 2.2 Characterization

For the chemical analysis, the samples were fused using NaHSO<sub>4</sub> as a flux reagent. The obtained material was then dissolved in HCl. The chemical composition of each sample was analyzed by induction-coupled plasma atomic emission spectrometry (ICP-AES), using Zn as the internal standard. Crystal structure characterization of the samples was performed by X-ray powder diffraction (XRD). The electrical resistivity of the samples was measured by means of a dc four probe method from 0.5 K to room temperature. The magnetic susceptibility measurements were performed in a field of 5000 Oe using a commercial SQUID magnetometer (Quantum Design Inc., MPMS-5) from 5 K to room temperature. The micro-Vickers hardness of the crystals was measured at room temperature. A load of 300 g was applied for 15 s and 10 impressions were recorded for the crystals. TG and DTA were performed between room temperature and 1473 K to study the oxidation resistivity of the crystals in air. A pulverized sample of about 25 mg was heated at a rate of 10  $Kmin^{-1}$ .

#### 3. Results and discussion

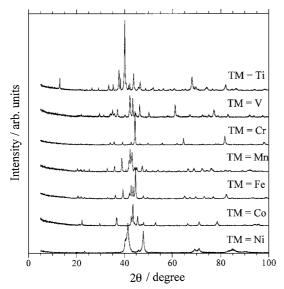
The arc melted samples were silver in color and exhibited a metallic lustre. The result of the chemical analysis shows that the chemical compositions before and after synthesis are almost the same. In addition, contamination

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**Fig. 1.** Powder XRD patterns for the Sc-TM-B (TM=Ti, Cr, Mn, Fe, Co and Ni) system; nominal composition is Sc:TM:B=1:3:1 (atomic ratio).

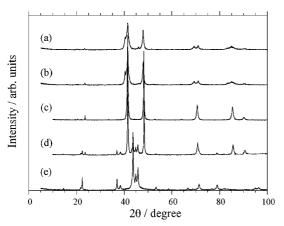


Fig. 2. Powder XRD patterns for  $ScNi_3B_{x}$ ; (a) x = 1.00 (20 at.% B), (b) x = 0.71 (15 at.% B), (c) x = 0.50 (11.1 at.% B), (d) x = 0.44 (10 at.% B) and (e) x = 0.21 (5 at.% B).

from the electrode (tungsten) and hearth (copper) could be disregarded in this study.

Fig. 1 shows powder XRD patterns for the Sc-TM-B (TM = Ti, V, Cr, Mn, Fe, Co and Ni) systems. As result, a new perovskite-type boride has been obtained in the system of Sc-Ni-B. Fig. 2 shows the powder XRD patterns for ScNi<sub>3</sub>B<sub>x</sub>; (a) x = 1.00 (20 at.% B), (b) x = 0.71 (15 at.% B), (c) x = 0.50 (11.1 at.% B), (d) x = 0.44 (10 at.% B), and (e) x = 0.21 (5 at.% B). In the case of (c), boron content x = 0.5, the XRD pattern corresponds to an almost single phase sample. Other samples include different phase(s). So we conclude that the chemical formula of the compound is ScNi<sub>3</sub>B<sub>0.5</sub>. This compound has the cubic perovskite-type structure (space group: Pm3m) with the lattice parameter a = 0.37760(7) nm. In the structure, Sc is at the corners of the cube. Ni is at the six face-centered sites and B at the

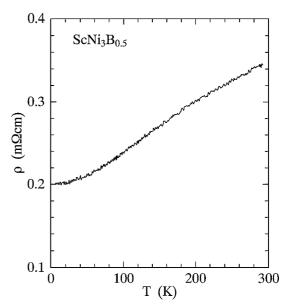
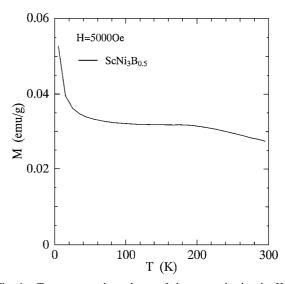


Fig. 3. Temperature dependence of the electrical resistivity for  $ScNi_3B_0$  5.



**Fig. 4.** Temperature dependence of the magnetization in H=5000 Oe for ScNi<sub>3</sub>B<sub>0.5</sub>.

body-centered site.

Fig. 3 shows the temperature dependence of the electrical resistivity for  $ScNi_3B_{0.5}$ . The  $ScNi_3B_{0.5}$  exhibits metallic behavior down to 4.2 K. No super-conductivity appears at the lowest temperature.

Fig. 4 shows the temperature dependence of the magnetization of  $ScNi_3B_{0.5}$  in a field H=5000 Oe. Magnetic susceptibility for  $ScNi_3B_{0.5}$  show Pauli paramagnetic behavior. No trace of superconductivity is found down to 2  $\kappa$ 

One of the important mechanical properties, the hardness [9,10], is measured for  $ScNi_3B_{0.5}$ . The micro-Vickers hardness for the  $ScNi_3B_{0.5}$  is  $4.6\pm0.1$  GPa.

Fig. 5 shows TG-DTA curves for ScNi<sub>3</sub>B<sub>0.5</sub>. The TG

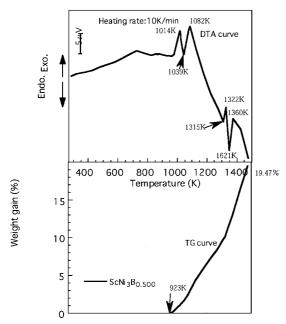


Fig. 5. TG-DTA curves for ScNi<sub>3</sub>B<sub>0.5</sub>.

analysis indicates that the onset temperature of the oxidation for  $ScNi_3B_{0.5}$  is 923 K. Sharp exothermic peaks of the DTA curve appeared at 1014 and 1082 K. The weight gain of  $ScNi_3B_{0.5}$  by heating in air up to 1473 K is 19.47%.  $Sc_2$   $O_3$ ,  $ScNiO_3$ , and Ni are identified as the oxidation products of  $ScNi_3B_{0.5}$ .

#### 4. Conclusions

A search for perovskite-type new borides in the Sc-TM-B (TM=Ti, V, Cr, Mn, Fe, Co and Ni) system has been carried out. We can draw the following conclusions from this study [11]:

- (1) A new perovskite-type boride has been discovered only for TM = Ni, the chemical formula of the compound is  $ScNi_3B_{0.5}$ .
- (2) ScNi<sub>3</sub>B<sub>0.5</sub> has cubic perovskite-type of structure (space group: Pm3m) with the lattice parameter a = 0.37760(7) nm.
- (3) ScNi<sub>3</sub>B<sub>0.5</sub> exhibits metallic behavior.
- (4) The magnetic susceptibility of ScNi<sub>3</sub>B<sub>0.5</sub> shows Pauli

- paramagnetism.
- (5) The micro-Vickers hardness of  $ScNi_3B_{0.5}$  is  $4.6\pm0.1$  GPa.
- (6) TG analysis indicates that the onset temperature of oxidation for ScNi<sub>3</sub>B<sub>0.5</sub> is 923 K.

Exothermic peaks in the DTA curve are found at 1014 and 1082 K.  $Sc_2O_3$ ,  $ScNiO_3$ , and Ni are identified as the oxidation products.

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